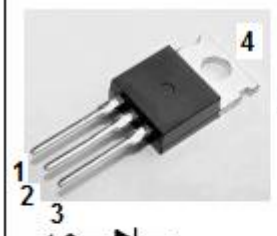
Ultrafast Rectifier

BYV32-200

FEATURES

- High surge capacity
- Low Forward Voltage
- Low Leakage Current
- 150℃ Operating Junction Temperature
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

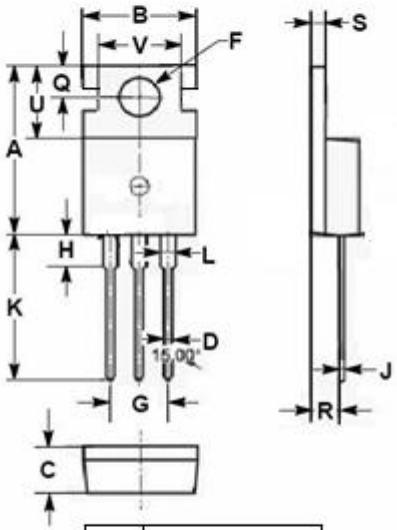


PIN:1 Anode
2 Cathode
3 Anode
4 Cathode

TO-220 Package

APPLICATIONS

- Power supply-output rectification
- Power management
- Instrumentation



DIM	mm MIN	mm MAX
A	15.50	15.90
B	9.80	10.20
C	4.20	4.50
D	0.70	0.90
F	3.40	3.70
G	4.98	5.18
H	2.68	2.90
J	0.44	0.60
K	12.80	13.40
L	1.20	1.45
Q	2.70	2.90
R	2.30	2.70
S	1.29	1.35
U	6.45	6.65
V	8.66	8.86

ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V_{RRM} V_{RWM} V_R	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current **Per Leg** (Rated V_R) **Total Device**	8 16	A
I_{FM}	Peak Repetitive Forward Current (Rated V_R, Square Wave,20kHz) **Per Diode Leg**	16	A
I_{FSM}	Nonrepetitive Peak Surge Current (Surge applied at rated load conditions half-wave, single phase, 60Hz)	100	A
T_J	Junction Temperature	-65~150	℃
T_{stg}	Storage Temperature Range	-65~150	℃

Fast Recovery Rectifier BYV32-200

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j\text{-}c}$	Thermal Resistance,Junction to Case	0.9	℃/W
$R_{th\ j\text{-}a}$	Thermal Resistance,Junction to Ambient	60	℃/W

ELECTRICAL CHARACTERISTICS(T_a=25℃) (Pulse Test: Pulse Width=300μs,Duty Cycle≤2%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V_F	Maximum Instantaneous Forward Voltage	I_F= 5A ;Tj=100℃ I_F= 20A ;Tj=25℃	0.85 1.15	V
I_R	Maximum Instantaneous Reverse Current	V_{RRM}= 200V	50	μA
t_{rr}	Maximum Reverse Recovery Time	IF =2A，di/dt = 50A/μs IF =0.5A，I_R =1A，I_{REC}=0.25A	35 25	ns